



24-Bit Analog-to-Digital Converter For Bridge Sensors

FEATURES

- Complete Front-End for Bridge Sensors
- Up to 23.5 Effective Bits
- **Onboard, Low-Noise PGA**
- **RMS Noise:** 17nV at 10SPS (PGA = 128) 44nV at 80SPS (PGA = 128)
- 19.2-Bit Noise-Free Resolution at Gain = 64
- Over 100dB Simultaneous 50Hz and 60Hz Rejection
- Flexible Clocking: Low-Drift Onboard Oscillator (±3%) **Optional External Crystal**
- Selectable Gains of 1, 2, 64, and 128 •
- Easy Ratiometric Measurements-External Voltage Reference up to 5V
- Selectable 10SPS or 80SPS Data Rates
- **Two-Channel Differential Input with Built-In Temperature Sensor (ADS1232)**
- Four-Channel Differential Input (ADS1234)
- **Simple Serial Digital Interface** .
- Supply Range: 2.7V to 5.3V
- -40°C to +105°C Temperature Range .

APPLICATIONS

- Weigh Scales
- Strain Gauges
- **Pressure Sensors**
- Industrial Process Control

DESCRIPTION

The ADS1232 and ADS1234 are precision 24-bit analog-to-digital converters (ADCs). With an onboard, low-noise programmable gain amplifier (PGA), precision delta-sigma ADC and internal oscillator, the ADS1232/4 provide a complete front-end solution for bridge sensor applications including weigh scales, strain gauges and pressure sensors.

The input multiplexer accepts either two (ADS1232) or four (ADS1234) differential inputs. The ADS1232 also includes an onboard temperature sensor to monitor ambient temperature. The onboard, low-noise PGA has a selectable gain of 1, 2, 64, or 128 supporting a full-scale differential input of ±2.5V, ±1.25V, ±39mV, or ±19.5mV. The delta-sigma ADC has 23.5-bit effective resolution and is comprised of a 3rd-order modulator and 4th-order digital filter. Two data rates are supported: 10SPS (with both 50Hz and 60Hz rejection) and 80SPS. The ADS1232/4 can be clocked externally using an oscillator or a crystal. There is also an internal oscillator available that requires no external components. Offset calibration is performed on-demand and the ADS1232/4 can be put in a low-power standby mode or shut off completely in power-down mode. All of the features of the ADS1232/4 are operated through simple pin-driven control. There are no digital registers to program in order to simplify software development. Data are output over an easily-isolated serial interface that connects directly to the MSP430 and other microcontrollers.

The ADS1232 is available in a TSSOP-24 package and the ADS1234 is in a TSSOP-28. Both are fully specified from -40°C to +105°C.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet. All trademarks are the property of their respective owners.







This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

ORDERING INFORMATION

For the most current package and ordering information, see the Package Option Addendum at the end of this data sheet, or see the TI website at www.ti.com.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

	ADS1232, ADS1234	UNIT
AVDD to AGND	-0.3 to +6	V
DVDD to DGND	-0.3 to +6	V
AGND to DGND	-0.3 to +0.3	V
Input Current	100, Momentary	mA
Input Current	10, Continuous	mA
Analog Input Voltage to AGND	-0.3 to AVDD + 0.3	V
Digital Input Voltage to DGND	-0.3 to DVDD + 0.3	V
Maximum Junction Temperature	+150	°C
Operating Temperature Range	-40 to +105	°C
Storage Temperature Range	-60 to +150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.



ELECTRICAL CHARACTERISTICS

All specifications at $T_A = -40^{\circ}$ C to $+105^{\circ}$ C, AVDD = DVDD = VREFP = +5V, and VREFN = AGND, unless otherwise noted.

		ADS1	232, ADS1234		
PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
Analog Inputs					
Full-Scale Input Voltage (AINP – AINN)		E	0.5V _{REF} /Gain		V
Common-Mode Input Range	AINxP or AINxN with respect to GND, Gain = 1, 2	AGND – 0.1		AVDD + 0.1	V
	Gain = 64, 128	AGND + 1.5V		AVDD - 1.5V	V
	Gain = 1		±3		nA
Differential Input Current	Gain = 2		±6		nA
	Gain = 64, 128		±3.5		nA
System Performance					
Resolution	No Missing Codes	24			Bits
	Internal Oscillator, SPEED = High	78	80	82.4	SPS
	Internal Oscillator, SPEED = Low	9.75	10	10.3	SPS
Data Rate	External Oscillator, SPEED = High		f _{CLK} /61,440		SPS
	External Oscillator, SPEED = Low		f _{CLK} /491,520		SPS
Digital Filter Settling Time	Full Settling		4		Conversions
	Differential Input, End-Point Fit Gain = 1, 2		±0.0002	±0.001	% of FSR ⁽¹⁾
Integral Nonlinearity (INL)	Differential Input, End-Point Fit Gain = 64, 128		±0.0004		% of FSR
Input Offset Error ⁽²⁾	Gain = 1		±0.2	±5	ppm of FS
	Gain = 128		±0.02	±1	ppm of FS
Input Offact Drift	Gain = 1		±0.3		µV/°C
Input Offset Drift	Gain = 128		±10		nV/°C
Gain Error ⁽³⁾	Gain = 1		±0.001	±0.02	%
Gam Enor	Gain = 128		±0.01	±0.1	%
Cain Drift	Gain = 1		±0.2		ppm/°C
Gain Drift	Gain = 128		±2.5		ppm/°C
Normal-Mode Rejection ⁽⁴⁾	Internal Oscillator, $f_{DATA} = 10$ SPS $f_{IN} = 50$ Hz or 60Hz, ±1Hz	100	110		dB
	External Oscillator, $f_{DATA} = 10SPS$ $f_{IN} = 50Hz$ or 60Hz, ±1Hz	120	130		dB
Common-Mode Rejection	at DC, Gain = 1, ΔV = 1V	95	110		dB
	at DC, Gain = 128, $\Delta V = 0.1V$	95	110		dB
Input-Referred Noise		Se	e Noise Perforn	nance Tables	
Power-Supply Rejection	at DC, Gain = 1, ΔV = 1V	100	120		dB
rower-Supply Rejection	at DC, Gain = 128, $\Delta V = 0.1V$	100	120		dB
Voltage Reference Input					
Voltage Reference Input (V _{REF})	$V_{REF} = VREFP - VREFN$	1.5	AVDD	AVDD + 0.1V	V
Negative Reference Input (VREFN)		AGND – 0.1		VREFP – 1.5	V
Positive Reference Input (VREFP)		VREFN + 1.5		AVDD + 0.1	V
Voltage Reference Input Current			10		nA

(1)

(2)

 $\label{eq:FSR} \begin{array}{l} \mbox{= full-scale range = V_{REF}/Gain.} \\ \mbox{Offset calibration can minimize these errors to the level of noise at any temperature.} \\ \mbox{Gain errors are calibrated at the factory (AVDD = +5V, all gains, T_A = +25°C).} \\ \mbox{Specification is assured by the combination of design and final production test.} \end{array}$ (3) (4)



ELECTRICAL CHARACTERISTICS (continued)

All specifications at $T_A = -40^{\circ}$ C to $+105^{\circ}$ C, AVDD = DVDD = VREFP = +5V, and VREFN = AGND, unless otherwise noted.

		ADS1:	ADS1232, ADS1234		
PARAMETER	CONDITIONS	MIN	TYP	TYP MAX	
Digital					
Logic Levels					
V _{IH}		0.7 DVDD		DVDD + 0.1	V
V _{IL}		DGND		0.2 DVDD	V
V _{OH}	I _{OH} = 1mA	DVDD - 0.4			V
V _{OL}	I _{OL} = 1mA			0.2 DVDD	V
Input Leakage	$0 < V_{IN} < DVDD$			±10	μΑ
External Clock Input Frequency (f _{CLKIN})		0.2	4.9152	8	MHz
Serial Clock Input Frequency (f _{SCLk}	()			5	MHz
Power Supply					
Power-Supply Voltage (AVDD, DVDD)		2.7		5.3	V
	Normal Mode, AVDD = 3V, Gain = 1, 2		600	1300	μA
	Normal Mode, AVDD = 3V, Gain = 64, 128		1350	2500	μA
Analog Supply Current	Normal Mode, AVDD = 5V, Gain = 1, 2		650	1300	μA
	Normal Mode, AVDD = 5V, Gain = 64, 128		1350	2500	μΑ
	Standby Mode		0.1	1	μA
	Power-Down		0.1	1	μA
	Normal Mode, DVDD = 3V, Gain = 1, 2		60	95	μA
	Normal Mode, DVDD = 3V, Gain = 64, 128		75	120	μA
Digital Supply Current	Normal Mode, DVDD = 5V, Gain = 1, 2		95	130	μA
	Normal mode, DVDD = 5V, Gain = 64, 128		75	120	μA
	Standby Mode, SCLK = High, DVDD = 3V		45	80	μA
	Standby Mode, SCLK = High, DVDD = 5V		65	80	μA
	Power-Down		0.2	1.3	μA
	Normal Mode, AVDD = DVDD = 3V, Gain = 1, 2		2	4.2	mW
	Normal Mode, AVDD = DVDD = 5V, Gain = 1, 2		3.7	7.2	mW
Power Dissipation, Total	Normal Mode, AVDD = DVDD = 3V, Gain = 64, 128		4.3	7.9	mW
	Normal Mode, AVDD = DVDD = 5V, Gain = 64, 128		7.1	13.1	mW
	Standby Mode, AVDD = DVDD = 5V		0.3	0.4	mW

NOISE PERFORMANCE

The ADS1232/4 offer outstanding noise performance that can be optimized for a given full-scale range using the on-chip programmable gain amplifier. Table 1 through Table 4 summarize the typical noise performance with inputs shorted externally for different gains, data rates, and voltage reference values.

The RMS and Peak-to-Peak noise are referred to the input. The Effective Number of Bits (ENOB) is defined as:

• ENOB = In (FSR/RMS noise)/In(2)

The Noise-Free Bits are defined as:

• Noise-Free Bits = In (FSR/Peak-to-Peak Noise)/In(2)

Where FSR (Full-Scale Range) = V_{REF} /Gain

Table 1. AVDD = 5V, V_{REF} = 5V, Data Rate = 10SPS

GAIN	RMS NOISE	PEAK-TO-PEAK NOISE ⁽¹⁾	ENOB (RMS)	NOISE-FREE BITS
1	420nV	1.79µV	23.5	21.4
2	270nV	900nV	23.1	21.4
64	19nV	125nV	22.0	19.2
128	17nV	110nV	21.1	18.4

(1) Peak-to-peak noise data are based on direct measurement.

Table 2. AVDD = 5V, V_{REF} = 5V, Data Rate = 80SPS

GAIN	RMS NOISE	PEAK-TO-PEAK NOISE ⁽¹⁾	ENOB (RMS)	NOISE-FREE BITS
1	1.36µV	8.3µV	21.8	19.2
2	850nV	5.5µV	21.5	18.8
64	48nV	307nV	20.6	18
128	44nV	247nV	19.7	17.2

(1) Peak-to-peak noise data are based on direct measurement.

Table 3. AVDD = 3V, V_{REF} = 3V, Data Rate = 10SPS

GAIN	RMS NOISE	PEAK-TO-PEAK NOISE ⁽¹⁾	ENOB (RMS)	NOISE-FREE BITS
1	450nV	2.8µV	22.6	20
2	325nV	1.8µV	22.1	19.7
64	20nV	130nV	21.2	18.5
128	18nV	115nV	20.3	17.6

(1) Peak-to-peak noise data are based on direct measurement.

Table 4. AVDD = 3V, V_{REF} = 3V, Data Rate = 80SPS

GAIN	RMS NOISE	PEAK-TO-PEAK NOISE ⁽¹⁾	ENOB (RMS)	NOISE-FREE BITS
1	2.2µV	12µV	20.4	17.9
2	1.2µV	6.8µV	20.2	17.8
64	54nV	340nV	19.7	17.1
128	48nV	254nV	18.9	16.5

(1) Peak-to-peak noise data are based on direct measurement of 1024 samples.



PIN CONFIGURATION



TEXAS INSTRUMENTS www.ti.com

SBAS350F-JUNE 2005-REVISED FEBRUARY 2008

PIN DESCRIPTIONS

	TERM	INAL	ANALOG/DIGITAL	A1		
NAME	ADS1232	ADS1234	INPUT/OUTPUT	DESCRIPTION		
DVDD	1	1	Digital	Digital Power Supply: 2.7V to 5.3V		
DGND	2	2	Digital	Digital Ground		
CLKIN/ XTAL1	3	3	Digital/Digital Input	External Clock Input: typically 4.9152MHz. Tie low to activate internal oscillator. Can also use external crystal across CLKIN/XTAL1 and XTAL2 pins. See text for more details.		
XTAL2	4	4	Digital	External crystal connection		
DGND	5	5	Digital	Digital Ground		
DGND	6	6	Digital	Digital Ground		
TEMP	7	-	Digital Input	Onboard Temperature Diode Enable		
				Input Mux Select Input pin (MSB)		
				Input Mux Select Input pin (LSB):		
		_		A1 A0 Channel		
A1 A0	- 8	7 8	Digital Input	0 0 AIN1		
		-		0 1 AIN2		
				1 0 AIN3		
				1 1 AIN4		
CAP	9	9	Analog	Gain Amp Bypass Capacitor Connection		
CAP	10	10	Analog	Gain Amp Bypass Capacitor Connection		
AINP1	11	11	Analog Input	Positive Analog Input Channel 1		
AINN1	12	12	Analog Input	Negative Analog Input Channel 1		
AINP3	-	13	Analog Input	Positive Analog Input Channel 3		
AINN3	-	14	Analog Input	Negative Analog Input Channel 3		
AINN4	-	15	Analog Input	Negative Analog Input Channel 4		
AINP4	-	16	Analog Input	Positive Analog Input Channel 4		
AINN2	13	17	Analog Input	Negative Analog Input Channel 2		
AINP2	14	18	Analog Input	Positive Analog Input Channel 2		
REFN	15	19	Analog Input	Negative Reference Input		
REFP	16	20	Analog Input	Positive Reference Input		
AGND	17	21	Analog	Analog Ground		
AVDD	18	22	Analog	Analog Power Supply, 2.7V to 5.3V		
				Gain Select		
				GAIN1 GAIN0 GAIN		
GAIN0	19	23		0 0 1		
GAIN1	20	24	Digital Input	0 1 2		
				1 0 64		
				1 1 128		
				Data Rate Select:		
				SPEED DATA RATE		
SPEED	21	25	Digital Input	0 10SPS		
				1 80SPS		
PDWN	22	26	Digital Input	Power-Down: Holding this pin low powers down the entire converter and resets the ADC.		
SCLK	23	27	Digital Input	Serial Clock: Clock out data on the rising edge. Also used to initiate Offset Calibration and Sleep modes. See text for more details.		
				Dual-Purpose Output:		
DRDY/ DOUT	24	28	Digital Output	Data Ready: Indicates valid data by going low.		
5001				Data Output: Outputs data, MSB first, on the first rising edge of SCLK.		



TYPICAL CHARACTERISTICS

At $T_A = +25^{\circ}C$, AVDD = DVDD = VREFP = 5V, and VREFN = AGND, unless otherwise noted.





TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^{\circ}C$, AVDD = DVDD = VREFP = 5V, and VREFN = AGND, unless otherwise noted.







TYPICAL CHARACTERISTICS (continued)

At T_A = +25°C, AVDD = DVDD = VREFP = 5V, and VREFN = AGND, unless otherwise noted.





www.ti.com SBAS350 TYPICAL CHARACTERISTICS (continued)

IEXAS RUMENTS

At $T_A = +25^{\circ}C$, AVDD = DVDD = VREFP = 5V, and VREFN = AGND, unless otherwise noted.





TYPICAL CHARACTERISTICS (continued)

At $T_A = +25^{\circ}C$, AVDD = DVDD = VREFP = 5V, and VREFN = AGND, unless otherwise noted.



OVERVIEW

The ADS1232 and ADS1234 are highly integrated, 24-bit ADCs that include an input multiplexer, low-noise PGA, third-order delta-sigma ($\Delta\Sigma$) modulator, and fourth-order digital filter. With input-referred RMS noise down to 17nV, the ADS1232/4 are ideally suited for measuring the very low signals produced by bridge sensors in applications such as weigh scales, strain gauges, and pressure sensors.

Clocking can be supplied by an external oscillator, an external crystal, or by a precision internal oscillator. Data can be output at 10SPS for excellent 50Hz and 60Hz rejection, or at 80SPS when higher speeds are needed. The ADS1232/4 are easy to configure, and all digital control is accomplished through dedicated pins; there are no registers to program. A simple two-wire serial interface retrieves the data.

ANALOG INPUTS (AINPx, AINNx)

The input signal to be measured is applied to the input pins AINPx and AINNx. The positive internal input is generalized as AINP, and the negative internal input generalized as AINN. The signal is selected through the input mux, which is controlled by pins A0 and A1 (ADS1234 only), as shown in Table 5. For the ADS1232, the A1 pin is replaced by the TEMP pin to activate the onboard diodes (see the Temperature Sensor section for more details). The ADS1232/4 accept differential input signals, but can also measure unipolar signals. When measuring unipolar (or single-ended signals) with respect to ground, connect the negative input (AINNx) to ground and connect the input signal to the positive input (AINPx). Note that when the ADS1232/4 are configured this way, only half of the converter full-scale range is used, since only positive digital output codes are produced.

Table 5. Input Channel Selection with A0 and A1				
. (ADS1234 only)				

MUX	PINS	SELECTED ANALOG INPUTS			
A1	A0	POSITIVE INPUT	NEGATIVE INPUT		
0	0	AINP1	AINN1		
0	1	AINP2	AINN2		
1	0	AINP3	AINN3		
1	1	AINP4	AINN3		

TEMPERATURE SENSOR (ADS1232 only)

SBAS350F-JUNE 2005-REVISED FEBRUARY 2008

On-chip diodes provide temperature-sensing capability. By setting the TEMP pin high, the selected analog inputs are disconnected and the inputs to the ADC are connected to the anodes of two diodes scaled to 1x and 80x in current and size, as shown in Figure 26. By measuring the difference in voltage of these diodes, temperature changes can be inferred from a baseline temperature. Typically, the difference in diode voltage is 111.7mV at 25°C with a temperature coefficient of $379\mu V/^{\circ}C$. With PGA = 1 and 2, the difference voltage output from the PGA will be 111.7mV and 223.4mV, respectively. With PGA = 64 and 128, it is impossible to use the temperature sensor function. A similar structure is used in the MSC1210 for temperature measurement. For more information, see TI application report SBAA100, Using the MSC121x as a High-Precision Intelligent Temperature Sensor, available for download at www.ti.com.



Figure 26. Measurement of the Temperature Sensor in the Input Multiplexer

LOW-NOISE PGA

The ADS1232/4 features a low-drift, low-noise PGA that provides a complete front-end solution for bridge sensors. A simplified diagram of the PGA is shown in Figure 27. It consists of two chopper-stabilized amplifiers (A1 and A2) and three accurately-matched resistors (R_1 , R_{F1} , and R_{F2}), which construct a differential front-end stage with a gain of 64, followed by gain stage A3. The PGA inputs are equipped with an EMI filter, as shown in Figure 27. The cut-off frequency of the EMI filter is 19.6MHz. If the PGA is set to 1 or 2, the gain-of-64 stage is bypassed and shut down to save power. With the combination of both gain stages, the PGA can be set to 64 or 128. The PGA of the ADS1232/4 can be set to 1, 2, 64, or 128 with pins GAIN1 (MSB) and GAIN0 (LSB). By using AVDD as the reference input, the bipolar input ranges from ±2.5V to ±19.5mV, while the unipolar ranges from 2.5V to 19.5mV. When the PGA is set to 1 or 2, the absolute inputs can go rail-to-rail without significant performance degradation. However, the inputs of the ADS1232/4 are protected with internal diodes connected to the power-supply rails. These diodes will clamp the applied signal to prevent it from damaging the input circuitry. On the other hand, when the PGA is set to 64 or 128, the operating input range is limited to (AGND + 1.5V) to (AVDD - 1.5V), in order to prevent saturating the differential front-end circuitry and degrading performance.



Figure 27. Simplified Diagram of the PGA



Bypass Capacitor

By applying a 0.1μ F external capacitor (C_{EXT}) across two capacitor pins and the combination of the internal $2k\Omega$ resistor R_{INT} on-chip, a low-pass filter (with a corner frequency of 720Hz) is created to bandlimit the signal path prior to the modulator input. This low-pass filter serves two purposes. First, the input signal is bandlimited to prevent aliasing as well as to filter out the high-frequency noise. Second, it attenuates the chopping residue from the PGA (for gains of 64 and 128 only) to improve temperature drift performance. It is not required to use high quality capacitors (such as ceramic or tantalum capacitors) for a general application. However, high quality capacitors such as poly are recommended for high linearity applications.

VOLTAGE REFERENCE INPUTS (REFP, REFN)

The voltage reference used by the modulator is generated from the voltage difference between REFP and REFN: $V_{REF} = REFP - REFN$. The reference inputs use a structure similar to that of the analog inputs. In order to increase the reference input impedance, a switching buffer circuitry is used to reduce the input equivalent capacitance. The reference drift and noise impact ADC performance. In order to achieve best results, pay close attention to the reference noise and drift specifications. A simplified diagram of the circuitry on the reference inputs is shown in Figure 28. The switches and capacitors can be modeled with an effective impedance of:

$$Z_{EFF} = \frac{1}{2f_{MOD}C_{BUF}}$$

Where:

 f_{MOD} = modulator sampling frequency (76.8kHz) C_{BUF} = input capacitance of the buffer

For the ADS1232/4:

TEXAS INSTRUMENTS www.ti.com

SBAS350F-JUNE 2005-REVISED FEBRUARY 2008





Figure 28. Simplified Reference Input Circuitry

ESD diodes protect the reference inputs. To prevent these diodes from turning on, make sure the voltages on the reference pins do not go below GND by more than 100mV, and likewise, do not exceed AVDD by 100mV:

GND – 100mV < (REFP or REFN) < AVDD + 100mV

CLOCK SOURCES

The ADS1232/4 can use an external clock source, external crystal, or internal oscillator to accommodate a wide variety of applications. Figure 29 shows the equivalent circuitry of the clock source. The CLK DETECT block determines whether the crystal oscillator/external clock signal is applied to the CLKIN/XTAL1 pin so that the internal oscillator is bypassed or activated. When the CLKIN/XTAL1 pin frequency is above ~200kHz, the CLK_DETECT output goes low and shuts down the internal oscillator. When the XIN pin frequency is below ~200kHz, the CLK_DETECT output goes high and activates the internal oscillator. It is highly recommended to hard-wire the CLKIN/XTAL1 pin to ground when the internal oscillator is chosen.



Figure 29. Equivalent Circuitry of the Clock Source

When the clock source is a crystal, simply connect the 4.9152MHz crystal across the CLKIN/XTAL1 and XTAL2 pins. Table 6 shows the recommended part numbers. Due to the low-power design of the parallel circuitry onboard, resonant driver both the CLKIN/XTAL1 and XTAL2 pins are only for use with external crystals; they should not be used as clock output drivers for external circuitry. No external capacitors are used with the crystal; it is recommended to place the crystal close to the part in order to reduce board stray capacitance for both the CLKIN/XTAL1 and XTAL2 pins and to insure proper operation.

Table 6. Recommended Crystals

MANUFACTURER	FREQUENCY	PART NUMBER
ECS	4.9152MHz	ECS-49-20-1
ECS	4.9152MHz	ECS-49-20-4

An external oscillator may be used by driving the CLKIN/XTAL1 pin directly. The Electrical Characteristics table shows the allowable frequency range.



FREQUENCY RESPONSE

The ADS1232/4 use a sinc⁴ digital filter with the frequency response ($f_{CLK} = 4.9152MHz$) shown in Figure 30. The frequency response repeats at multiples of the modulator sampling frequency of 76.8kHz. The overall response is that of a low-pass filter with a –3dB cutoff frequency of 3.32Hz with the SPEED pin tied low (10SPS data rate) and 11.64Hz with the SPEED pin tied high (80SPS data rate).



Figure 30. Frequency Response

To help see the response at lower frequencies, Figure 31(a) illustrates the response out to 100Hz, when the data rate = 10SPS. Notice that signals at multiples of 10Hz are rejected, and therefore simultaneous rejection of 50Hz and 60Hz is achieved.

The benefit of using a $sinc^4$ filter is that every frequency notch has four zeros on the same location. This response, combined with the low drift internal oscillator, provides an excellent normal-mode rejection of line-cycle interference.

Figure 31(b) shows the zoom in plot for both 50Hz and 60Hz notches with the SPEED pin tied low (10SPS data rate). With only a \pm 3% variation of the internal oscillator, over 100dB of normal-mode rejection is achieved.



Figure 31. Frequency Response Out To 100Hz

The ADS1232/4 data rate and frequency response scale directly with clock frequency. For example, if f_{CLK} increases from 4.9152MHz to 6.144MHz when the SPEED pin is tied high, the data rate increases from 80SPS to 100SPS, while notches also increase from 80Hz to 100Hz. Note that this is only possible when the external clock source is applied.



SETTLING TIME

After changing the input multiplexer, the first data are fully settled. In both the ADS1232/4, the digital filter is allowed to settle after toggling either the A1 or A0 pin. <u>Toggling</u> any of these digital pins will hold the DRDY/DOUT line high until the digital filter is fully settled. For example, if A0 changes from low to high, selecting a different input channel, DRDY/DOUT immediately goes high, and DRDY/DOUT goes low when fully-settled data are ready for retrieval. There is no need to discard any data. Figure 32 shows the timing of the DRDY/DOUT line as the input multiplexer changes.

In certain instances, large and/or abrupt changes in input will require four data cycles to settle. One example of such a change would be an external multiplexer in front of the ADS1232/4, which can cause large changes in input voltage simply by switching input channels. Another example would be toggling the TEMP pin, which switches the internal AINP, AINN signals to connect to either the external AINPx, AINNx pins or to the TEMP diode (see Figure 26).

Note that when settling data, five readings may be required. If the change in input occurs in the middle of the first conversion, four more full conversions of the fully-settled input are required to get fully-settled data. Discard the first four readings because they contain only partially-settled data.Figure 33 illustrates the settling time for the ADS1232/4 in Continuous Conversion mode.



Figure 32. Example of Settling Time After Changing the Input Multiplexer

SYMBOL	DESCRIPTION ⁽¹⁾	MIN	MAX	UNITS	
t _S	Setup time for changing the A	40	50	μs	
+	Settling time (DRDY/DOUT	SPEED = 1	51	51	ms
4	t ₁ held high)	SPEED = 0	401	401	ms

(1) Values given for $f_{CLK} = 4.9152$ MHz. For different f_{CLK} frequencies, scale proportional to CLK period. Expect a ±3% variation when an internal oscillator is used.



Figure 33. Settling Time in Continuous Conversion Mode





DATA RATE

The ADS1232/4 data rate is set by the SPEED pin, as shown in Table 7. When SPEED is low, the data rate is nominally 10SPS. This data rate provides the lowest noise, and also has excellent rejection of both 50Hz and 60Hz line-cycle interference. For applications requiring fast data rates, setting SPEED high selects a data rate of nominally 80SPS.

Table 7. Data Rate Settings

	DATA RATE					
SPEED PIN	Internal Oscillator or 4.9152MHz Crystal	External Oscillator				
0	10SPS	f _{CLKIN} / 491,520				
1	80SPS	f _{CLKIN} / 61,440				

DATA FORMAT

The ADS1232/4 output 24 bits of data in binary two's complement format. The least significant bit (LSB) has a weight of $0.5V_{REF}/(2^{23} - 1)$. The positive full-scale input produces an output code of 7FFFFFh and the negative full-scale input produces an output code of 800000h. The output clips at these codes for signals exceeding full-scale. Table 8 summarizes the ideal output codes for different input signals.

Table 8. Ideal Output Code vs Input Signal ⁽	Table 8	. Ideal	Output	Code	vs In	put Signa	l ⁽¹⁾
---	---------	---------	--------	------	-------	-----------	------------------

INPUT SIGNAL V _{IN} (AINP – AINN)	IDEAL OUTPUT CODE
≥ +0.5V _{REF} /Gain	7FFFFh
(+0.5V _{REF} /Gain)/(2 ²³ - 1)	000001h
0	000000h
(-0.5V _{REF} /Gain)/(2 ²³ - 1)	FFFFFh
≤ –0.5V _{REF} /Gain	800000h

(1) Excludes effects of noise, INL, offset, and gain errors.

DATA READY/DATA OUTPUT (DRDY/DOUT)

This digital output pin serves two purposes. First, it indicates when new data are ready by going low. Afterwards, on the first rising edge of SCLK, the DRDY/DOUT pin changes function and begins outputting the conversion data, most significant bit (MSB) first. Data are shifted out on each subsequent SCLK rising edge. After all 24 bits have been retrieved, the pin can be forced high with an additional SCLK. It will then stay high until new data are ready. This configuration is useful when polling on the status of DRDY/DOUT to determine when to begin data retrieval.

SERIAL CLOCK INPUT (SCLK)

This digital input shifts serial data out with each rising edge. This input has built-in hysteresis, but care should still be taken to ensure a clean signal. Glitches or slow-rising signals can cause unwanted additional shifting. For this reason, it is best to make sure the rise-and-fall times of SCLK are less than 50ns.



DATA RETRIEVAL

The ADS1232/4 continuously convert the analog input signal. To retrieve data, wait until DRDY/DOUT goes low, as shown in Figure 34. After this occurs, begin shifting out the data by applying SCLKs. Data are shifted out MSB first. It is not required to shift out all 24 bits of data, but the data must be retrieved before new data are updated (within t_7) or else it will be overwritten. Avoid data retrieval during the update period (t_6). DRDY/DOUT remains at the state of the last bit shifted out until it is taken high (see t_6),

indicating that new data are being updated. To avoid having DRDY/DOUT remain in the state of the last bit, the user can shift SCLK to force DRDY/DOUT high, as shown in Figure 35. This technique is useful when a host controlling the device is polling DRDY/DOUT to determine when data are ready.



Figure 34. Data Retrieval Timing

SYMBOL	DESCRIPTION		MIN	ТҮР	MAX	UNITS
t ₂	DRDY/DOUT low to first SCLK	rising edge	0			ns
t ₃	SCLK positive or negative pulse	e width	100			ns
t ₄	SCLK rising edge to new data b	it valid: propagation			50	ns
t ₅	SCLK rising edge to old data bit	valid: hold time	0			ns
t ₆ ⁽¹⁾	Data updating: no readback allo	wed	39			μs
t ₇ ⁽¹⁾	Conversion time (1/date rate)	SPEED = 1		12.5		ms
	Conversion time (1/data rate)		100		ms	

(1) Values given for f_{CLK} = 4.9152MHz. For different f_{CLK} frequencies, scale proportional to CLK period.



Figure 35. Data Retrieval with DRDY/DOUT Forced High Afterwards



OFFSET CALIBRATION

Offset calibration can be initiated at any time to remove the ADS1232/4 inherited offset error. To initiate offset calibration, apply at least two additional SCLKs after retrieving 24 bits of data. Figure 36 shows the timing pattern. The 25th SCLK will send DRDY/DOUT high. The falling edge of the 26th SCLK will begin the calibration cycle. Additional SCLK pulses may be sent after the 26th SCLK; however, activity on SCLK should be minimized during offset calibration for best results.

When the calibration is completed, $\overline{DRDY}/DOUT$ goes low, indicating that new data are ready. The analog input pins are disconnected within the ADC and the appropriate signal is applied internally to perform the calibration. The first conversion after a calibration is fully settled and valid for use. The offset calibration takes exactly the same time as specified in (t₈) right after the falling edge of the 26th SCLK.



Figure 36. Offset-Calibration Timing

SYMBOL	DESCRIPTION	MIN	MAX	UNITS	
t8 ⁽¹⁾	First data ready after collibration	SPEED = 1	101.28	101.29	ms
	First data ready after calibration	SPEED = 0	801.02	801.03	ms

(1) Values given for $f_{CLK} = 4.9152$ MHz. For different f_{CLK} frequencies, scale proportional to CLK period. Expect a ±3% variation when an internal oscillator is used.

STANDBY MODE

Standby mode dramatically reduces power consumption by shutting down most of the circuitry. In Standby mode, the entire analog circuitry is powered down and only the clock source circuitry is awake to reduce the wake-up time from the Standby mode. To enter Standby mode, simply hold SCLK high after DRDY/DOUT goes low; see Figure 37. Standby mode can be initiated at any time during readback; it is not necessary to retrieve all 24 bits of data beforehand.

When t₁₀ has passed with SCLK held high, Standby mode will activate. DRDY/DOUT stays high when Standby mode begins. SCLK must remain high to stay in Standby mode. To exit Standby mode (wakeup), set SCLK low. The first data after exiting Standby mode is valid.



SYMBOL	DESCRIPTION		MIN	MAX	UNITS			
t9 ⁽¹⁾	SCLK high after DRDY/DOUT goes low	SPEED = 1	0	12.44	ms			
	to activate Standby mode	SPEED = 0	0	99.94	ms			
t ₁₀ ⁽¹⁾	Standby made activation time	SPEED = 1	12.46		ms			
	Standby mode activation time	SPEED = 0	99.96		ms			
t ₁₁ ⁽¹⁾	Data ready offer exiting Standby mode	SPEED = 1	52.51	52.51	ms			
	Data ready after exiting Standby mode		401.9	401.9	ma			

Figure 37. Standby Mode Timing (can be used for single conversions)

Values given for f_{CLK} = 4.9152MHz. For different f_{CLK} frequencies, scale proportional to CLK period. Expect a ±3% variation when an (1) internal oscillator is used.

SPEED = 0

401.8

401.8

ms



STANDBY MODE WITH OFFSET-CALIBRATION

Offset-calibration can be set to run immediately after exiting Standby mode. This is useful when the ADS1232/4 is put in Standby mode for long periods of time, and offset-calibration is desired afterwards to compensate for temperature or supply voltage changes. To force an offset-calibration with Standby mode, shift 25 SCLKs and take the SCLK pin high to enter Standby mode. Offset-calibration then begins after wake-up; see Figure 38 for the appropriate timing. Note the extra time needed after wake-up for calibration before data are ready. The first data after Standby mode with offset-calibration is fully settled and can be used right away.



Figure 38. Standby Mode with Offset-Calibration Timing (can be used for single conversions)

SYMBOL	DESCRIPTION		MIN	MAX	UNITS
+ (1)	Data ready after exiting Standby mode		103	103	ms
¹ 12'	t ₁₂ ⁽¹⁾ Data ready after exiting Standby mode and calibration	SPEED = 0	803	803	ms

Values given for f_{CLK} = 4.9152MHz. For different f_{CLK} frequencies, scale proportional to CLK period. Expect a ±3% variation when an internal oscillator is used.



POWER-UP SEQUENCE

When powering up the ADS1232/34, AVDD and DVDD must be powered up before the PDWN pin goes high, as shown in Figure 39. If PDWN is not controlled by a microprocessor, a simple RC delay circuit must be implemented, as shown in Figure 40.

POWER-DOWN MODE

Power-Down mode shuts down the entire ADC circuitry and reduces the total power consumption close to zero. To enter Power-Down mode, simply hold the PDWN pin low. Power-Down mode also resets the entire circuitry to free the ADC circuitry from locking up to an unknown state. Power-Down mode can be initiated at any time during readback; it is not necessary to retrieve all 24 bits of data beforehand. Figure 41 shows the wake-up timing from Power-Down mode.



SBAS350F-JUNE 2005-REVISED FEBRUARY 2008

Figure 39. Power-Up Timing Sequence



Figure 40. RC Delay Circuit



Figure 41. Wake-Up Timing from Power-Down Mode

SYMBOL	DESCRIPTION	ТҮР	UNITS	
		Internal clock	7.95	μs
t ₁₃	Wake-up time after Power-Down mode	External clock	0.16	μs
	Crystal oscillator ⁽¹⁾		5.6	ms
t ₁₄ ⁽²⁾	PDWN pulse width	26 (min)	μs	

(1) No capacitors on CLKIN/XTAL1 or XTAL2 outputs.

(2) Value given for $f_{CLK} = 4.9152$ MHz. For different f_{CLK} frequencies, the scale is proportional to the CLK period except for a ±3% variation when an internal oscillator is used.

APPLICATION EXAMPLES

Weigh-Scale System

Figure 42 shows a typical ADS1232 hook-up as part of a weigh-scale system. In this setup, the ADS1232 is configured to channel one input with a gain of 128 at a 10SPS data rate. Note that the internal oscillator is used by grounding the CLKIN/XTAL1 pin. The user can also apply either a 4.9152MHz crystal across the CLKIN/XTAL1 and XTAL2 pins, or simply apply a clock to the CLKIN/XTAL1 pin. For a typical 2mV/V load cell, the maximum output signal is approximately 10mV for a single +5V excitation voltage. The ADS1232/4 can achieve 18.4 noise-free bits at 10SPS when the PGA = 128 (refer to Table 1). With the extra software filtering/averaging (typically done by a microprocessor), an extra bit can be expected.

Noise–Free Counts =
$$(2^{BIT}_{Eff}) \left(\frac{FS_{LC}}{FS_{AD}} \right)$$

Where:

 BIT_{EFF} = effective noise-free bits (18.4 + 1 bit from software filtering/averaging)

 FS_{LC} = full-scale output of the load cell (10mV) FS_{AD} = full-scale input of the ADS1232/4 (39mV when PGA = 128)



Therefore:

Noise–Free Counts =
$$(2^{(18.4+1)})(\frac{10mV}{39mV}) = 177,385$$

With +5V supply voltage, 177,385 noise-free counts can be expected from the ADS1232/4 with the onboard PGA set to 128.

Thermocouple

See Figure 43 for the ADS1232 in a thermocouple application. In this example, a type *k* thermocouple is used; the temperature range is from -260° C to $+900^{\circ}$ C when the gain is set to 64 to maximize the full input range of the ADS1232. R₁ and a REF1004-2.5V are used to set the common-mode voltage to 2.5V for ungrounded junction thermocouples. With a gain of 128, the ADS1232 input has a typical noise of $17nV_{RMS}$ for extremely high-resolution applications.

If either a wider temperature range application is required (up to +1350°C, for example), or a grounded junction thermocouple is used, pin 1 of the thermocouple can be grounded (see Figure 44). When the gain is set to 2, the ADS1232 input has a typical 500nV offset error and a noise level of $270nV_{RMS}$, which is good for all kinds of low-voltage output sensors. Note that to calculate the actual thermocouple temperature, the ADS1232 internal temperature sensor can be accessed in order to measure the cold junction temperature along with the thermocouple reading.









Figure 43. Ungrounded Junction Thermocouple Application





Figure 44. Grounded Junction Thermocouple Application





RTDs and Thermistors

Figure 45 shows a typical schematic for a style 2 (three-wire) RTD application. R_1 and R_2 are used to excite the RTD as well as establish the common-mode voltage of the ADS1232 PGA.

By using both differential channels of the ADS1232, the temperature change in lead resistance, R_L , can be eliminated. This condition is accomplished by using the following formula:

(AINP1 - AINN1) - 2(AINP2 - AINN2).



Figure 45. Style 2 (Three-Wire) RTD Schematic

SUMMARY OF SERIAL INTERFACE WAVEFORMS





Revision History

Chan	ges from Revision E (October 2007) to Revision F	Page
• Cł	nanged AVDD to deltaV in Common-Mode Rejection section in Electrical Characteristics table	3
• Cł	nanged AVDD to deltaV in Power-Supply Rejection section in Electrical Characteristics table	3
Chan	ges from Revision D (September 2007) to Revision E	Page
• Co	prrected unit values in Electrical Characteristics table	3
Chan	ges from Revision C (June 2006) to Revision D	Page
• De	eleted Logic Level V _{IH} row for CLKIN/XTAL test condition in Electrical Characteristics	3
• Ac	dded offset drift and gain drift histogram plots to Typical Characteristics (Figure 9 to Figure 16)	9
• Cł	nanged difference voltage output for PGA = 2 from 323.4mV to 223.4mV in Temperature Sensor section	13
• Ac	dded text to Voltage Reference Inputs section regarding reference and drift noise	14
• Cł	nanged Z _{EFF} equation	15
• Cł	nanged Figure 28	15
• Cł	nanged Figure 29	15
• De	eleted last sentence of Clock Sources section	15
• Cł	nanged text in Settling Time section	17
• Cł	nanged Figure 32	17
	nanged Figure 33	
• De	eleted 2nd sentence of Serial Clock Input section	18
• Ac	dded Power-Up Sequence section, with new text and two new figures (Figure 39 and Figure 40).	23
• Cł	nanged Figure 42	25
• Cł	nanged Figure 43	25
• Cł	nanged Figure 44	26
• Cł	nanged Figure 45	27

•	Deleted last row from Absolute Maximum Ratings table.	2
•	Changed Analog Inputs section of Electrical Characteristics table	3
•	Changed the typical value in last row of Voltage Reference Input section of Electrical Characteristics table	3
•	Added footnote 1 to Table 1, Table 2, Table 3, and Table 4.	5
•	Changed fourth sentence in Temperature Sensor section of Overview.	13
•	Added fifth and sixth sentences to Temperature Sensor section of Overview.	13
•	Added fourth and fifth sentences to Low-Noise PGA section of Overview.	14
•	Changed Figure 27.	14
•	Changed t ₁₁ to t ₁₀ in third paragraph of Standby Mode section of Overview.	21
•	Changed min and max variables of t ₁₀ row in table below Figure 37.	21
•	Changed Figure 41.	23
•	Added last row and second footnote to table below Figure 41	23



www.ti.com

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Peak Temp ⁽³⁾	Samples (Requires Login)
ADS1232IPW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
ADS1232IPWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
ADS1232IPWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
ADS1232IPWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
ADS1234IPW	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
ADS1234IPWG4	ACTIVE	TSSOP	PW	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
ADS1234IPWR	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	
ADS1234IPWRG4	ACTIVE	TSSOP	PW	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



www.ti.com

21-May-2010

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com

TAPE AND REEL INFORMATION

REEL DIMENSIONS

TEXAS INSTRUMENTS





TAPE AND REEL INFORMATION

TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

*A	Il dimensions are nominal												
	Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	ADS1232IPWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
	ADS1234IPWR	TSSOP	PW	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

TEXAS INSTRUMENTS

www.ti.com

PACKAGE MATERIALS INFORMATION

14-Jul-2012



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ADS1232IPWR	TSSOP	PW	24	2000	367.0	367.0	38.0
ADS1234IPWR	TSSOP	PW	28	2000	367.0	367.0	38.0

PW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G28)

PLASTIC SMALL OUTLINE



NOTES:

A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 B. This drawing is subject to change without notice.

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153





All linear dimensions are in millimeters. Α.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations. E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





All linear dimensions are in millimeters. Α.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations. E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products		Applications					
Audio	www.ti.com/audio	Automotive and Transportation	www.ti.com/automotive				
Amplifiers	amplifier.ti.com	Communications and Telecom	www.ti.com/communications				
Data Converters	dataconverter.ti.com	Computers and Peripherals	www.ti.com/computers				
DLP® Products	www.dlp.com	Consumer Electronics	www.ti.com/consumer-apps				
DSP	dsp.ti.com	Energy and Lighting	www.ti.com/energy				
Clocks and Timers	www.ti.com/clocks	Industrial	www.ti.com/industrial				
Interface	interface.ti.com	Medical	www.ti.com/medical				
Logic	logic.ti.com	Security	www.ti.com/security				
Power Mgmt	power.ti.com	Space, Avionics and Defense	www.ti.com/space-avionics-defense				
Microcontrollers	microcontroller.ti.com	Video and Imaging	www.ti.com/video				
RFID	www.ti-rfid.com						
OMAP Applications Processors	www.ti.com/omap	TI E2E Community	e2e.ti.com				
Wireless Connectivity	www.ti.com/wirelessconnectivity						

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2013, Texas Instruments Incorporated